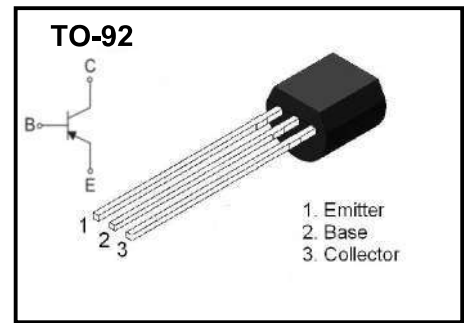


**PNP Plastic-Encapsulate Transistors**

**Switching and Applications**

- ◆High Voltage: BC546,  $V_{CE0} = -65V$
- ◆Low Noise: BC559, BC560
- ◆Complement to BC546/547/548/549/BC550



**Absolute Maximum Ratings (Ta=25°C)**

Parameter	Symbol	Value	Unit
Collector-Base Voltage	$BV_{CBO}$	-80 -50 -30	V
Collector-Emitter Voltage	$BV_{CEO}$	-65 -45 -30	V
Emitter-Base Voltage	$BV_{EBO}$	-5	V
Collector Current	$I_C$	-100	mA
Collector Power Dissipation	$P_C$	500	mW
Junction Temperature Storage Temperature	$T_j, T_{stg}$	150 -55 ~ +150	°C

**Electrical Characteristics (Ta=25°C)**

Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Collector cut-off current	$I_{CBO}$	$V_{CB} = -30V, I_E = 0$			-15	nA
Emitter cut-off current	$I_{EBO}$	$V_{EB} = -5V, I_C = 0$			-15	nA
DC current gain	$h_{FE}$	$V_{CE} = -5V, I_C = -2mA$	110		800	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -10mA, I_B = -0.5mA$ $I_C = -100mA, I_B = -5mA$			-0.30 -0.65	V
Base -emitter saturation voltage	$V_{BE(sat)}$	$I_C = -10mA, I_B = -0.5mA$ $I_C = -100mA, I_B = -5mA$			-1.0	V
Transition frequency	$f_T$	$V_{CE} = -5V, I_B = -10mA$		200		MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = -10V, I_E = 0, f = 1MHz$			6	pF

**$h_{FE}$  Classification**

Classification	A	B	C
$h_{FE}$	110-220	200-450	420-800

Typical Characteristics

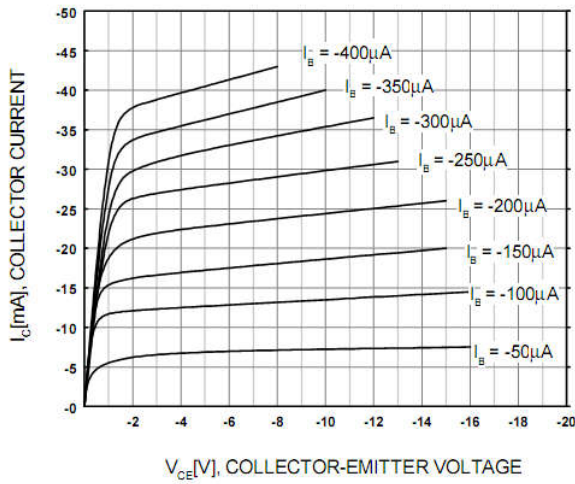


Figure 1. Static Characteristic

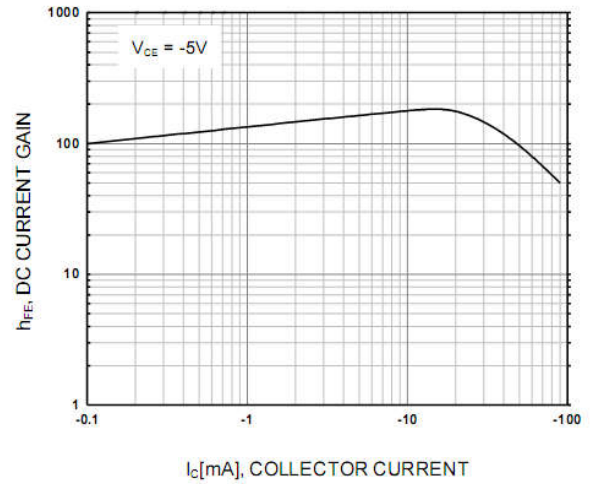


Figure 2. DC current Gain

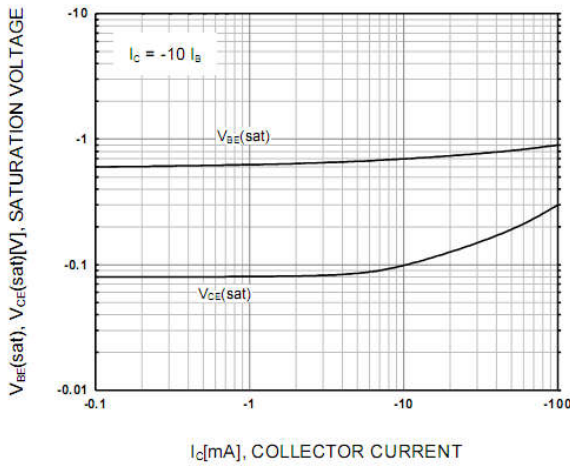


Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

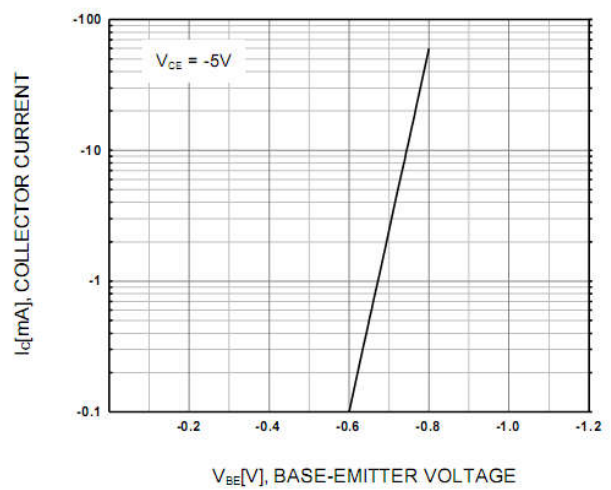


Figure 4. Base-Emitter On Voltage

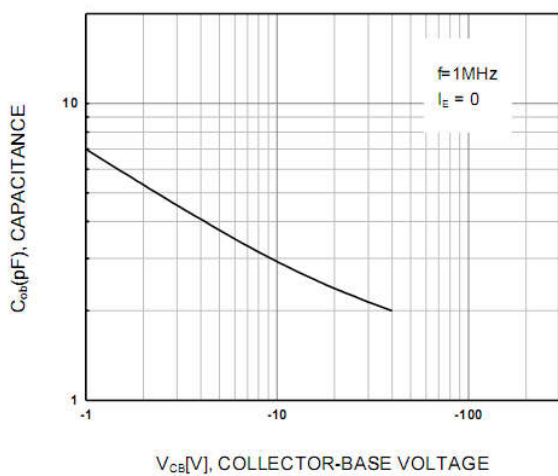


Figure 5. Output Capacitance

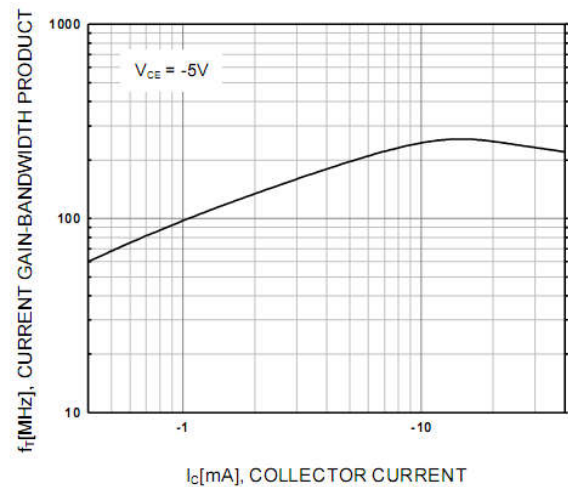


Figure 6. Current Gain Bandwidth Product

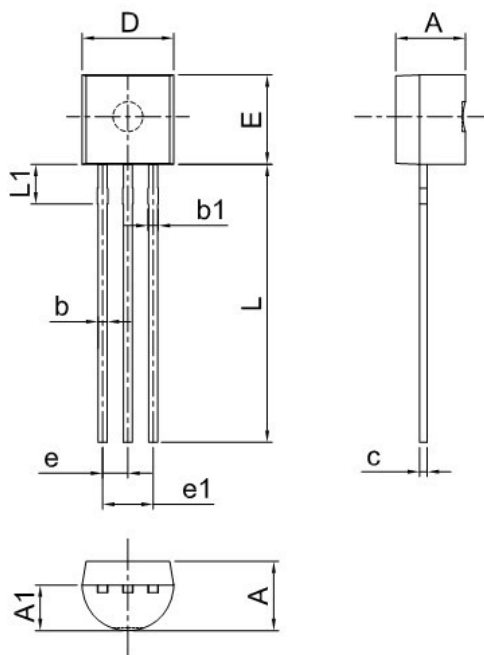
**Ordering information**

Package	Packing Description	Base Quantity
TO-92	Bulk	1000pcs/Bag
	Tape	2000pcs/Box

**Package Dimensions**

**TO-92**

Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	3.30	3.70	0.130	0.146
A1	2.30	2.70	0.091	0.106
b	0.40	0.50	0.016	0.020
b1	0.50	0.70	0.020	0.028
c	0.35	0.45	0.014	0.018
D	4.45	4.70	0.175	0.185
E	4.40	4.65	0.173	0.183
e	1.17	1.37	0.046	0.054
e1	2.34	2.64	0.092	0.104
L	13.50	14.50	0.531	0.571
L1	1.80	2.20	0.071	0.087



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